SWITCHMODE™ Power Rectifier

... using the Schottky Barrier principle with a platinum barrier metal. These state-of-the-art devices have the following features:

- Guardring for Stress Protection
- Low Forward Voltage
- 150°C Operating Junction Temperature
- Epoxy Meets UL94, VO at 1/8"

Mechanical Characteristics:

- · Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 units per plastic tube
- Marking: B2045P

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	
Average Rectified Forward Current (Rated V _R , T _C = 135°C)	I _{F(AV)}	20	A
	I _{FRM}	20	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	1 _{FSM}	150	А
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)	I _{RRM}	1.0	А
Storage Temperature Range	T _{stg}	-65 to +175	°C
Operating Junction Temperature	ŤJ	-65 to +150	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs



ON Semiconductor™

http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 20 AMPERES 45 VOLTS





CASE 221A TO-220AB PLASTIC

MARKING DIAGRAM



YY = Year WW = Work Week B2045P= Device Code AKA = Diode Polarity

ORDERING INFORMATION

Device	Package	Shipping	
MBR2045CTP	TO-220	50 Units/Rail	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.0	°C/W

ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 1) ($i_F = 10$ Amps, $T_C = 125$ °C) ($i_F = 20$ Amps, $T_C = 125$ °C) ($i_F = 20$ Amps, $T_C = 25$ °C)	V _F	0.57 0.72 0.84	Volts
Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, T_C = 125°C) (Rated dc Voltage, T_C = 25°C)	İR	15 0.1	mA

^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤[2.0%

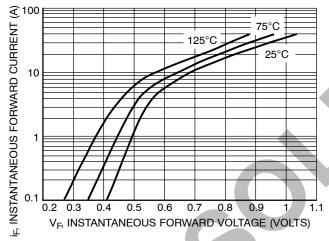


Figure 1. Maximum Forward Voltage

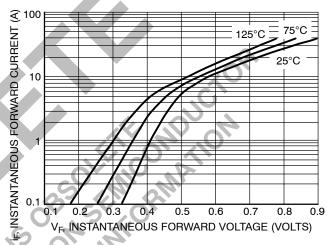


Figure 2. Typical Forward Voltage

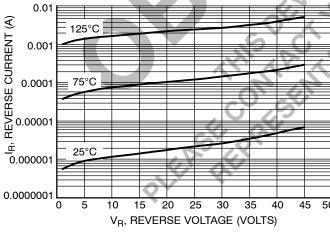


Figure 3. Typical Reverse Current

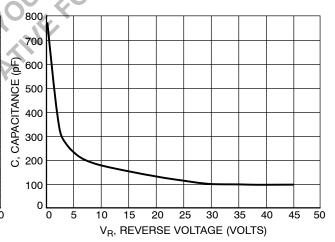


Figure 4. Typical Capacitance

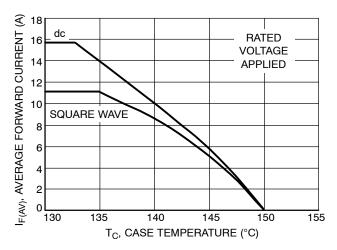


Figure 5. Current Derating, Case, Per Diode

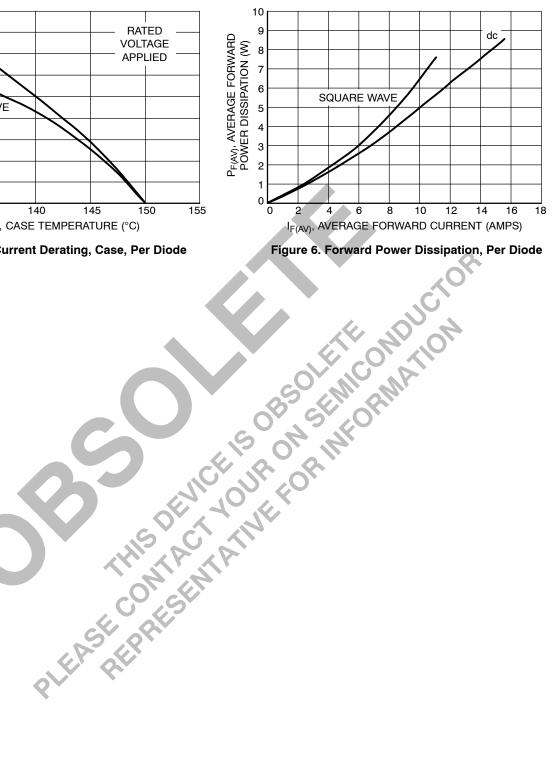
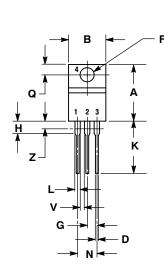


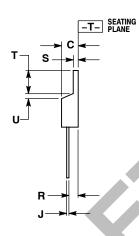
Figure 6. Forward Power Dissipation, Per Diode

PACKAGE DIMENSIONS

TO-220 THREE-LEAD TO-220AB

CASE 221A-09 **ISSUE AA**





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982
- CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

J J			INC	CHES	MILLIN	IETERS
<u> </u>		DIM	MIN	MAX	MIN	MAX
A		A	0.570	0.620	14.48	15.75
		В	0.380	0.405	9.66	10.28
U L		C	0.160	0.190	4.07	4.82
		D	0.025	0.035	0.64	0.88
I		F.	0.142	0.147	3.61	3.73
		G	0.095	0.105	2.42	2.66
I		H	0.110	0.155	2.80	3.93
Į		J	0.018	0.025	0.46	0.64
Ī		K	0.500	0.562	12.70	14.27
R →	← //	L	0.045	0.060	1.15	1.52
		N	0.190	0.210	4.83	5.33
J →		Q	0.100	0.120	2.54	3.04
		R	0.080	0.110	2.04	2.79
4		S	0.045	0.055	1.15	1.39
		- 1	0.235	0.255	5.97	6.47
4		Ü	0.000	0.050	0.00	1.27
		V	0.045		1.15	
	A	Z		0.080	-32	2.04
N A	CE IS OBSO					

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